NSN 5961-01-061-6530

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-061-6530 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and mounting hardware **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 2.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 12.00 amperes source cutoff current and 60.00 amperes source cutoff current **Power Rating Per Characteristic:** 120.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release5782 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No Fiig:

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Demilitarization: